

IXFX210N17T Datasheet



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	IXFX210N17T-DG
Manufacturer	IXYS
Manufacturer Product Number	IXFX210N17T
Description	MOSFET N-CH 170V 210A PLUS247-3
Detailed Description	N-Channel 170 V 210A (Tc) 1150W (Tc) Through Hole PLUS247™-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

IXFX210N17T

Series:

GigaMOS™

FET Type:

N-Channel

Drain to Source Voltage (Vdss):

170 V

Drive Voltage (Max Rds On, Min Rds On):

10V

Vgs(th) (Max) @ Id:

5V @ 4mA

Vgs (Max):

±20V

FET Feature:

-

Operating Temperature:

-55°C ~ 175°C (Tj)

Supplier Device Package:

PLUS247™-3

Base Product Number:

IXFX210

Manufacturer:

IXYS

Product Status:

Obsolete

Technology:

MOSFET (Metal Oxide)

Current - Continuous Drain (Id) @ 25°C:

210A (Tc)

Rds On (Max) @ Id, Vgs:

7.5mOhm @ 60A, 10V

Gate Charge (Qg) (Max) @ Vgs:

285 nC @ 10 V

Input Capacitance (Ciss) (Max) @ Vds:

18800 pF @ 25 V

Power Dissipation (Max):

1150W (Tc)

Mounting Type:

Through Hole

Package / Case:

TO-247-3 Variant

Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

REACH Status:

REACH Unaffected

HTSUS:

8541.29.0095

OUR CERTIFICATE

DiGi provide top-quality products and perfect service for customer worldwide through standardization, technological innovation and continuous improvement. DiGi through third-party certification, we stricly control the quality of products and services. Welcome your RFQ to

Email: Info@DiGi-Electronics.com



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.